

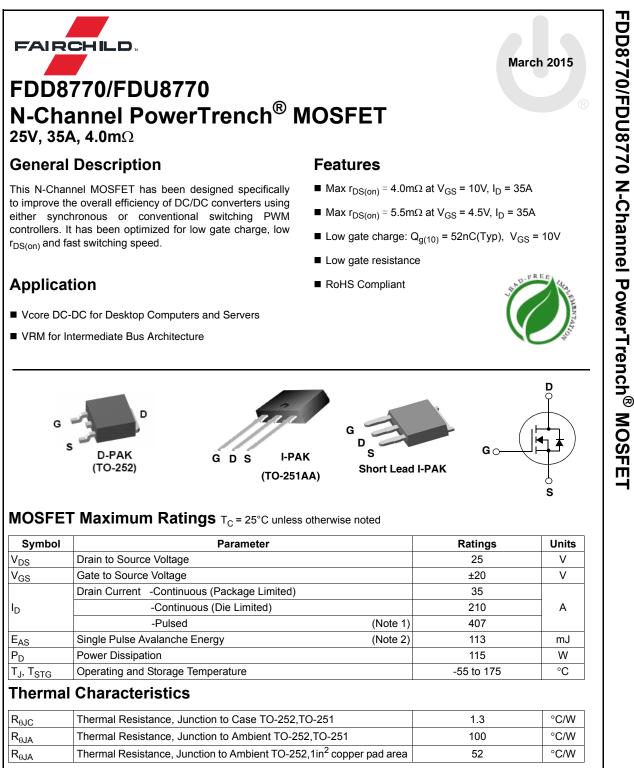
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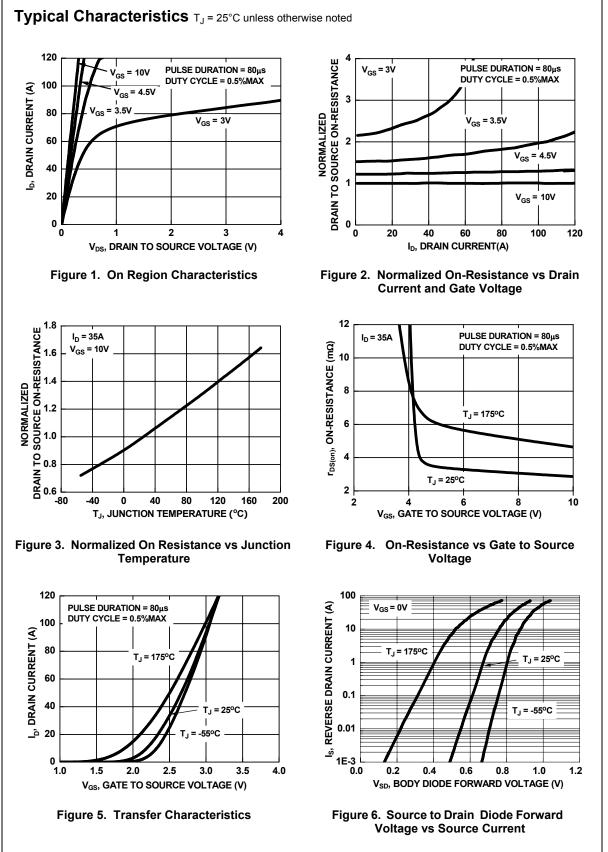
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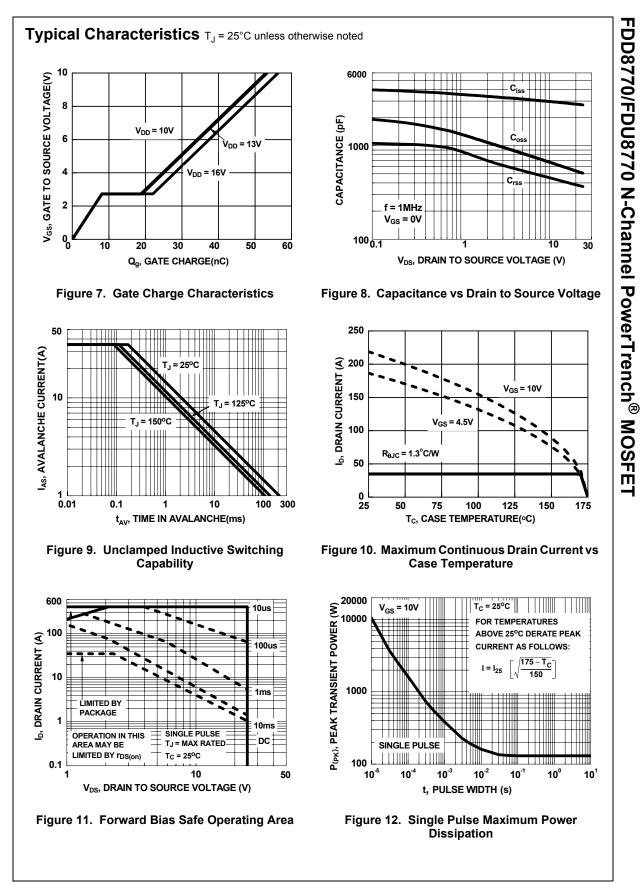


Package Marking and Ordering Information

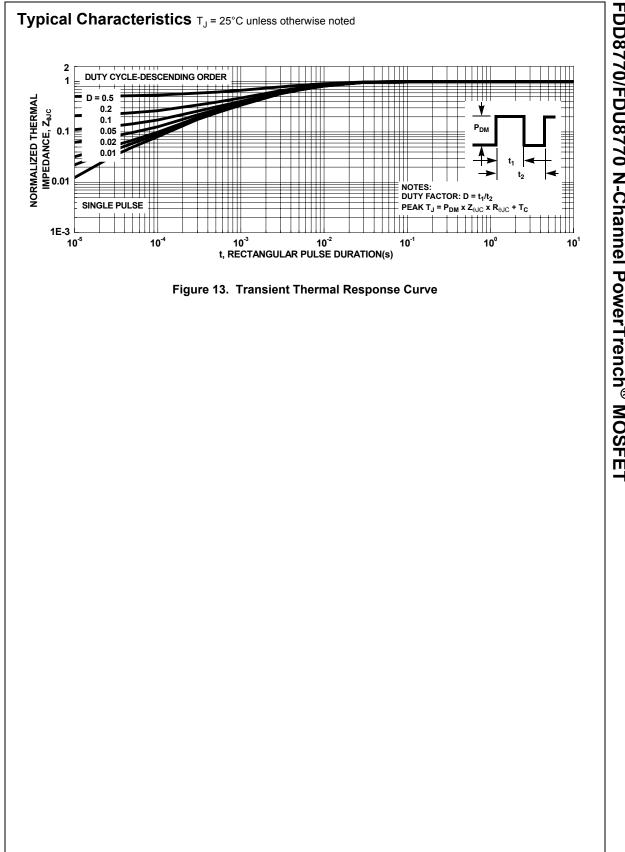
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDD8770	FDD8770	TO-252AA	13"	16mm	2500 units
FDU8770	FDU8770	TO-251AA	N/A(Tube)	N/A	75 units
FDU8770	FDU8770_F071	TO-251AA	N/A(Tube)	N/A	75 units

Symbol	Parameter	Test Conditions		Тур	Max	Units
Off Chara	cteristics					
B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _{GS} = 0V				V
ΔB _{VDSS}	Breakdown Voltage Temperature	$I_D = 250 \mu A$, referenced to		13.6		mV/°C
ΔT_J	Coefficient	25°C				
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 20V,			1	μA
088	° °	$V_{GS} = 0V$ $T_J = 150^{\circ}C$			250	
I _{GSS}	Gate to Source Leakage Current	V _{GS} = ±20V			±100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \mu A$	1.2	1.6	2.5	V
$\frac{\Delta V_{GS(th)}}{\Delta T_{.l}}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \mu A$, referenced to $25^{\circ}C$		-5.9		mV/°C
		V _{GS} = 10V, I _D = 35A		3.3 4.0		
	Desig to Course On Desigtance	V _{GS} = 4.5V, I _D = 35A			5.5	
	Drain to Source On Resistance	$V_{GS} = 10V, I_D = 35A$ T ₁ = 175°C		4.8	5.9	mΩ
C _{oss} C _{rss}	Output Capacitance Reverse Transfer Capacitance	v _{DS} = 13V, v _{GS} = 0V, -f = 1MHz		685 450	915 675	pF pF
C _{iss}	Input Capacitance	V _{DS} = 13V, V _{GS} = 0V,		2795	3720 915	pF pF
		f = 1MHz		450	675	ρ- Ω
R _g	Gate Resistance			1.5		52
Switching	g Characteristics					
t _{d(on)}	Turn-On Delay Time			10	20	ns
t _r	Rise Time	V _{DD} = 13V, I _D = 35A V _{GS} = 10V, R _{GS} = 5Ω		12	22	ns
	Turn-Off Delay Time	$v_{\rm GS} = 10v, R_{\rm GS} = 522$		49	78	ns
t _{d(off)}				25	40	ns
	Fall Time			52	73	nC
t _f	Fall Time Total Gate Charge	$V_{GS} = 0V$ to $10V$ $V_{GS} = 12V$				nC
t _{d(off)} t _f Q _g Q _g		$V_{\text{DD}} = 0V \text{ to } 5V$ $V_{\text{DD}} = 13V$		29	41	
t _f Q _g	Total Gate Charge	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$		8.1	41	nC
t _f Q _g Q _g Q _{gs}	Total Gate Charge Total Gate Charge	$V_{\text{DD}} = 0V \text{ to } 5V$ $V_{\text{DD}} = 13V$			41	nC nC
t _f Q _g Q _g Q _{gs} Q _{gd}	Total Gate Charge Total Gate Charge Gate to Source Gate Charge	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$		8.1	41	
t _f Q _g Q _{gs} Q _{gd} Drain-Sou	Total Gate Charge Total Gate Charge Gate to Source Gate Charge Gate to Drain "Miller"Charge urce Diode Characteristics	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$		8.1	41	nC
t _f Q _g Q _{gs} Q _{gd} Drain-Sou	Total Gate ChargeTotal Gate ChargeGate to Source Gate ChargeGate to Drain "Miller"Charge	$V_{GS} = 0V \text{ to } 5V$ $V_{DD} = 13V$ $I_D = 35A$ $I_g = 1.0mA$		8.1 11		
t _f Q _g Q _g Q _{gs} Q _{gd}	Total Gate Charge Total Gate Charge Gate to Source Gate Charge Gate to Drain "Miller"Charge urce Diode Characteristics	$V_{GS} = 0V \text{ to } 5V$ $I_D = 35A$ $I_g = 1.0mA$ $V_{GS} = 0V, I_S = 35A$		8.1 11 0.84	1.25	nC





FDD8770/FDU8770 Rev. 1.2







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